



STGP4M65DF2 Information

Heisener.com

Part Number STGP4M65DF2

Manufacturer STMicroelectronics

Category Discrete Semiconductor Products

Transistors - IGBTs - Single

Description IGBT M SERIES 650V 4A LOW LOSS

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

For Reference Only

Website: https://www.heisener.com
E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









STGP4M65DF2 Specifications

Manufacturer Part Number	STGP4M65DF2
Manufacturer	STMicroelectronics
Category	Discrete Semiconductor Products
	Transistors - IGBTs - Single
Package	TO-220-3
Series	M
IGBT Type	Trench Field Stop
Voltage - Collector Emitter Breakdown (Max)	650V
Current - Collector (Ic) (Max)	8A
Current - Collector Pulsed (Icm)	16A
Vce(on) (Max) @ Vge, Ic	2.1V @ 15V, 4A
Power - Max	68W
Switching Energy	40μJ (on), 136μJ (off)
Input Type	Standard
Gate Charge	15.2nC
Td (on/off) @ 25°C	12ns/86ns
Test Condition	400V, 4A, 47 Ohm, 15V
Reverse Recovery Time (trr)	133ns
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-220-3
Supplier Device Package	TO-220AB
	Report errors?

STGP4M65DF2 Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

STGP4M65DF2 Payment Methods



















STGP4M65DF2 Shipping Methods













If you have any question about STGP4M65DF2, please do not hesitate to contact us!

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